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40HF(R) SERIES

STANDARD RECOVERY DIODES **Stud Version**

Features

- High surge current capability
- Stud cathode and stud anode version
- Leaded version available
- Types up to 1600V V_{RRM}

40 A

Typical Applications

- Battery charges
- Converters
- Power supplies
- Machine tool controls
- Welding

Major Ratings and Characteristics

Parameters		40HF(R)		Units
		10 to 120	140, 160	
$I_{F(AV)}$		40	40	A
	@ T_C	140	110	°C
$I_{F(RMS)}$		62		A
I_{FSM}	@50Hz	570		A
	@ 60Hz	595		A
I^2t	@50Hz	1600		A^2s
	@ 60Hz	1450		A^2s
V_{RRM}	range	100 to 1200	1400, 1600	V
T_J	range	- 65 to 190	- 65 to 160	°C

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM}, maximum repetitive peak reverse voltage V	V_{RSM}, maximum non-repetitive peak reverse voltage V	I_{RRM} max. @ $T_J = T_J$ max. mA
40HF(R)	10	100	200	9
	20	200	300	
	40	400	500	
	60	600	700	
	80	800	900	
	100	1000	1100	
	120	1200	1300	
	140	1400	1500	4.5
	160	1600	1700	

Forward Conduction

Parameter		40HF(R) 10 to 120	40HF(R) 140, 160	Units	Conditions		
$I_{F(AV)}$	Max. average forward current	40	40	A	180° conduction, half sine wave		
	@ Case temperature	140	110	°C			
$I_{F(RMS)}$	Max. RMS forward current	62		A			
I_{FSM}	Max. peak, one-cycle forward, non-repetitive surge current	570		A	t = 10ms	No voltage reapplied	Sinusoidal half wave, Initial $T_J = T_J$ max.
		595			t = 8.3ms		
		480			t = 10ms	100% V_{RRM} reapplied	
		500			t = 8.3ms		
I^2t	Maximum I^2t for fusing	1600		A^2s	t = 10ms	No voltage reapplied	
		1450			t = 8.3ms		
		1150			t = 10ms	100% V_{RRM} reapplied	
		1050			t = 8.3ms		
$I^2\sqrt{t}$	Maximum $I^2\sqrt{t}$ for fusing	16000		$A^2\sqrt{s}$	t = 0.1 to 10ms, no voltage reapplied		
$V_{F(TO)}$	Value of threshold voltage (up to 1200V)	0.65		V	$T_J = T_J$ max.		
$V_{F(TO)}$	Value of threshold voltage (for 1400V, 1600V)	0.76			$T_J = T_J$ max.		
r_f	Value of forward slope resistance (up to 1200V)	4.29		mΩ	$T_J = T_J$ max.		
r_f	Value of forward slope resistance (for 1400V, 1600V)	3.8			$T_J = T_J$ max.		
V_{FM}	Max. forward voltage drop	1.30	1.50	V	I_{pk} = 125A, T_J = 25°C, t_p = 400µs rectangular wave		

Thermal and Mechanical Specifications

	Parameter	40HF(R) 10 to 120	40HF(R) 140 to 160	Units	Conditions
T_J	Max. junction operating temperature range	-65 to 190	-65 to 160	°C	
T_{stg}	Max. storage temperature range	-65 to 190	-65 to 160		
R_{thJC}	Max. thermal resistance, junction to case	0.95		K/W	DC operation
R_{thCS}	Max. thermal resistance, case to heatsink	0.25			Mounting surface, smooth, flat and greased
T	Max. allowed mounting torque ±10%	2.3 - 3.4		Nm	Not lubricated threads
		20 - 30		lbf · in	
wt	Approximate weight	17 (0.6)		g (oz)	unleaded device
	Case style	DO-203AB (DO5)			See Outline Table

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistence R_{thJC} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.14	0.10	K/W	T_J = T_J max.
120°	0.16	0.17		
90°	0.21	0.22		
60°	0.30	0.31		
30°	0.50	0.50		

Ordering Information Table

Device Code

40	HF	R	160	M
①	②	③	④	⑤

1 - 40 = Standard device
41 = Not isolated lead
42 = Isolated lead with silicone sleeve
(Red = Reverse polarity)
(Blue = Normal polarity)

2 - Standard diode

3 - None = Stud Normal Polarity (Cathode to Stud)
R = Stud Reverse Polarity (Anode to Stud)

4 - Voltage code: Code x 10 = V_{RRM} (See Voltage Ratings table)

5 - None = Stud base DO-203AB (DO-5) 1/4" 28UNF-2A
M = Stud base DO-203AB (DO-5) M6 X 1

40HF(R) Series

Outlines Table